# NSN 5961-00-501-1146

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-501-1146

**Inclosure Material:** 

Metal

**Overall Length:** 

1.252 inches

#### **Overall Diameter:**

0.500 inches

#### Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage, dc and 7.0 emitter to base voltage, instantaneous

#### **Current Rating Per Characteristic:**

7.00 amperes source cutoff current and 5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

35.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Test Data Document:**

13499-352-0704 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

#### Unit Of Measure:

--

#### Demilitarization:

No

### Fiig:

A110a0